



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group Art Unit 258
Examiner S. Loke

Amendment

#3/a

John C. Huang, et al.

High Electron Mobility Transistor
and Method of Manufacture

Serial No. 697,830

Filed: May 9, 1991

HON. COMMISSIONER OF PATENTS

AND TRADEMARKS

WASHINGTON, DC 20231

Sir:

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MAILING CERTIFICATE

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner of Patents and Trademarks, Washington, D.C. 20231 on
January 7, 1992

Name Denis G. Maloney Reg. No. 29,670

Signature *Denis G. Maloney*

Date Jan 7, 1992

AMENDMENT

In response to the Office Action dated October 29, 1991, please enter the following amendment.

In the Claims

1

1.

(Amended) A [high electron mobility] transistor comprises: